

# 4V Drive Nch MOSFET

# **RSH125N03**

#### Structure

Silicon N-channel MOSFET

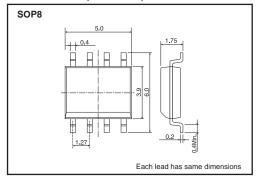
#### Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (SOP8) .

#### Application

Power switching, DC / DC converter.

#### •Dimensions (Unit : mm)



#### Packaging specifications

| Туре      | Package                      | Taping |
|-----------|------------------------------|--------|
|           | Code                         | ТВ     |
|           | Basic ordering unit (pieces) | 2500   |
| RSH125N03 | 3                            | 0      |

#### ●Absolute maximum ratings (Ta=25°C)

|                                | -          | , ,                |            |      |
|--------------------------------|------------|--------------------|------------|------|
| Parameter                      |            | Symbol             | Limits     | Unit |
| Drain-source voltage           |            | VDSS               | 30         | V    |
| Gate-source voltage            |            | Vgss               | 20         | V    |
| Drain current                  | Continuous | ID                 | ±12.5      | A    |
|                                | Pulsed     | I <sub>DP</sub> *1 | ±50        | A    |
| Source current<br>(Body diode) | Continuous | ls                 | 1.6        | A    |
|                                | Pulsed     | I <sub>SP</sub> *1 | 6.4        | A    |
| Total power dissipation        |            | Pd *2              | 2          | W    |
| Channel temperature            |            | Tch                | 150        | °C   |
| Storage temperature            |            | Tstg               | -55 to 150 | °C   |
|                                |            |                    |            |      |

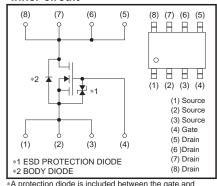
∗1 Pw≤10μs, Duty cycle≤1%

\*2 Mounted on a ceramic board.

#### Thermal resistance

| Parameter                     | Symbol      | Limits | Unit   |
|-------------------------------|-------------|--------|--------|
| Channel to ambient            | Rth (ch-a)* | 62.5   | °C / W |
| * Mounted on a ceramic board. |             |        |        |

#### Inner circuit



A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

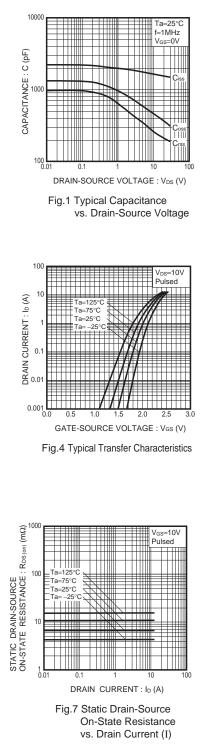
### •Electrical characteristics (Ta=25°C)

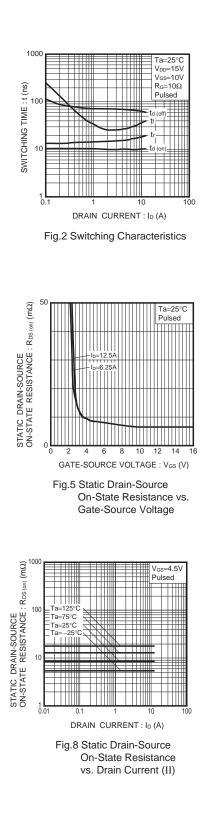
| Parameter                               | Symbol                 | Min. | Тур. | Max. | Unit | Conditions                                   |
|---|------------------------|------|------|------|------|--|
| Gate-source leakage                     | Igss                   | -    | _    | 10   | μΑ   | V <sub>GS</sub> =20V, V <sub>DS</sub> =0V    |
| Drain-source breakdown voltage          | V(BR) DSS              | 30   | _    | -    | V    | I <sub>D</sub> =1mA, V <sub>GS</sub> =0V     |
| Zero gate voltage drain current         | IDSS                   | -    | _    | 1    | μΑ   | VDS=30V, VGS=0V                              |
| Gate threshold voltage                  | VGS (th)               | 1.0  | -    | 2.5  | V    | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA    |
| Static drain-source on-state resistance | R <sub>DS (on)</sub> * | _    | 6.5  | 9.1  |      | I <sub>D</sub> =12.5A, V <sub>GS</sub> =10V  |
|   |                        | -    | 8.6  | 12.1 | mΩ   | I <sub>D</sub> =12.5A, V <sub>GS</sub> =4.5V |
|   |                        | -    | 9.3  | 13.1 |      | ID=12.5A, VGs=4V                             |
| Forward transfer admittance             | Y <sub>fs</sub> *      | 10   | _    | -    | S    | I <sub>D</sub> =12.5A, V <sub>DS</sub> =10V  |
| Input capacitance                       | Ciss                   | -    | 1670 | -    | pF   | V <sub>DS</sub> =10V                         |
| Output capacitance                      | Coss                   | -    | 470  | -    | рF   | V <sub>GS</sub> =0V                          |
| Reverse transfer capacitance            | Crss                   | -    | 270  | -    | pF   | f=1MHz                                       |
| Turn-on delay time                      | td (on) *              | -    | 10   | -    | ns   | I <sub>D</sub> =6.25A, V <sub>DD</sub> ≒15V  |
| Rise time                               | tr *                   | -    | 17   | -    | ns   | V <sub>GS</sub> =10V                         |
| Turn-off delay time                     | td (off) *             | -    | 69   | -    | ns   | RL=2.40Ω                                     |
| Fall time                               | tr *                   | _    | 30   | -    | ns   | Rg=10Ω                                       |
| Total gate charge                       | Qg *                   | _    | 20   | 28   | nC   | V <sub>DD</sub> ≒15V                         |
| Gate-source charge                      | Q <sub>gs</sub> *      | _    | 4.2  | -    | nC   | V <sub>GS</sub> =5V                          |
| Gate-drain charge                       | Q <sub>gd</sub> *      | -    | 8.0  | -    | nC   | I <sub>D</sub> =12.5A                        |

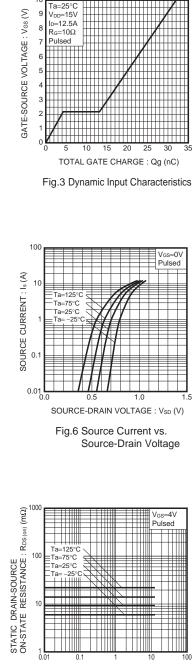
## •Body diode characteristics (Source-Drain) (Ta=25°C)

| Parameter       | Symbol            | Min. | Тур. | Max. | Unit | Conditions                   |
|-----------------|-------------------|------|------|------|------|------------------------------|
| Forward voltage | V <sub>SD</sub> * | _    | -    | 1.2  | V    | Is=6.4A, V <sub>GS</sub> =0V |

#### •Electrical characteristic curves







DRAIN CURRENT : ID (A)

Fig.9 Static Drain-Source On-State Resistance vs. Drain Current (III)

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